# NSN 5962-01-294-5746



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-294-5746 **Body Length:** Between 0.750 inches and 0.865 inches **Body Width:** Between 0.240 inches and 0.260 inches **Body Height:** Between 0.150 inches and 0.185 inches **Operating Tempurature Range:** +0.0/+70.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** Radar set an/aps-13 (v) 2 **Features Provided:** Programmable and schottky and 3-state output and w/enable and bipolar **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## **Terminal Type And Quantity:**

16 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

## **Demilitarization:**

Yes - demil/mli

Fiig:

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